

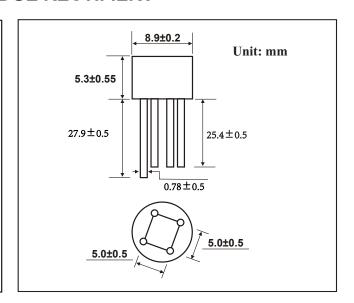
#### WOB SILICON BRIDGE RECTIFIERV

# **FEATURES**

- •The plastic package carries Underwrites Laboratory Flammability Classification 94V-0
- •Construction utilizes void-free molded plastic technique
- High reliability
- $\bullet$  High temperature soldering guaranteed:260  $^{\circ}\text{C}/10$  seconds at terminals
- Component in accordance to RoHs 2015/863 and WEEE 2012/19/EU

# **MECHANICAL DATA**

- Case style:WOB molded plastic
- Mounting position: Any



#### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

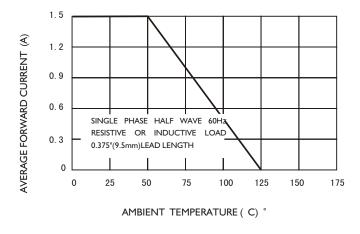
Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate by 20%.

		Symbols	2W005	2W01	2W02	2W04	2W06	2W08	2W10	Units
Maximum Recurrent Peak Reverse Voltage		Vrrm	50	100	200	400	600	800	1000	Volts
Maximum RMS Voltage		Vrms	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage		VDC	50	100	200	400	600	800	1000	Volts
Maximum Average Forward Rectified Current		I(AV)	2.0							Amp
Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load (JEDEC method)		lfsm	40						Amps	
Maximum Instantaneous Forward Voltage at 2. 0A DC		VF	1.0							Volts
Maximum DC Reverse Current at rated DC blocking voltage	T <sub>A</sub> =25 °C	l <sub>R</sub>	10							μΑ
	T <sub>A</sub> =100°C	HV.	500							
Operating junction and storage temperature range		Тј Тsтg	-40 to +125							°C

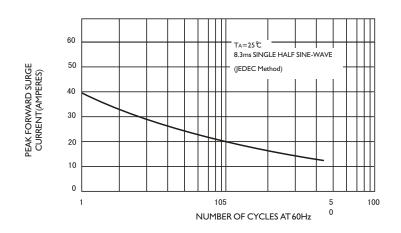


## **RATINGS AND CHARACTERISTIC CURVES**

### **F1G.1-FORWARD CURRENT DERATING CURVE**



## FIG.2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT



## FIG.3-TYPCAL INSTANTANEOUS FORWARD CHARACTERISTICS

10

0.01

# INSTANTANEOUS FORWARD CURRENT( AMPERES) 0.1 TA=25 C Pulse Width=300 sµ 1% Duty Cycle 0. 01

0. 2 0. 4 0. 6 0. 8 1. 0 1. 2 1. 4 INSTANTANEOUS FORWARD VOLTAGE (VOLTS)

#### FIG.4-TYPICAL REVERSE CHARACTERISTICS

